

**FEATURES**

- \* 2.0 inch (50.8 mm) MATRIX HEIGHT.
- \* LOW POWER REQUIREMENT.
- \* EXCELLENT CHARACTERS APPEARANCE..
- \* HIGH BRIGHTNESS & HIGH CONTRAST.
- \* 5×7 ARRAY WITH X-Y SELECT.
- \* HIGH BRIGHTNESS & HIGH CONTRAST.
- \* SOLID STATE RELIABILITY.

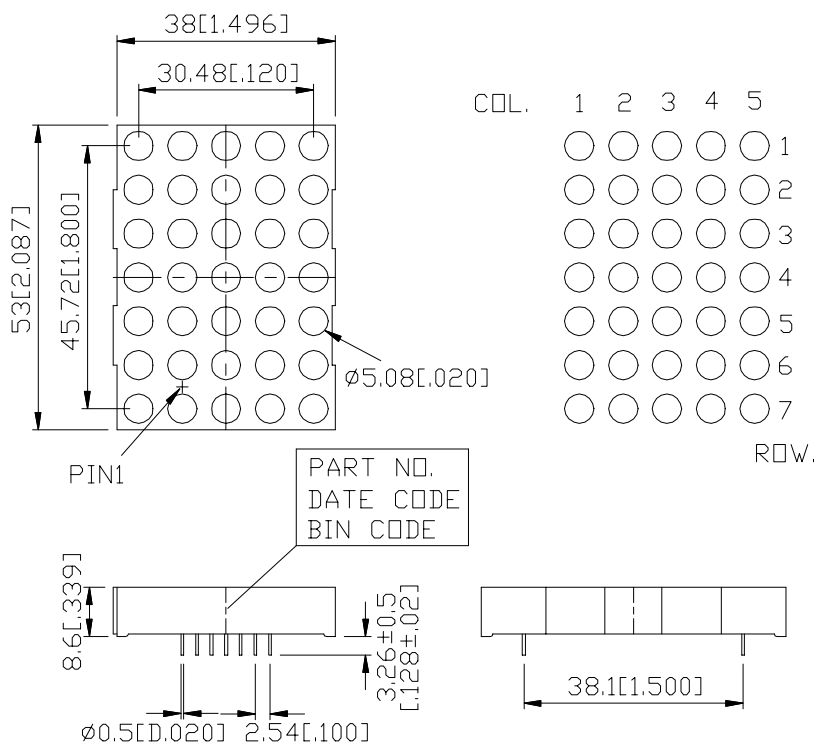
**DESCRIPTION**

The LTP-2157AKD is a 2.0 inch (50.8 mm) matrix height 5×7 dot matrix display. AllInGaP Hyper Red LED chips, which are made from AllInGaP on a non-transparent GaAs substrate, and has a gray face and white dot color.

**DEVICE**

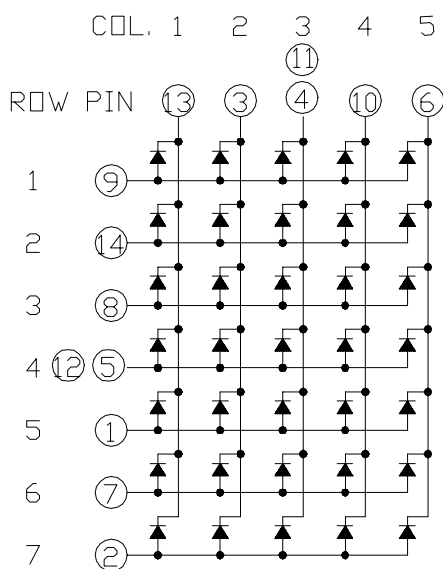
<b>PART NO.</b>	<b>DESCRIPTION</b>
AllInGaP Hyper Red	CATHODE COLUMN
LTP-2157AKD	ANODE ROW

## PACKAGE DIMENSIONS



NOTES: All dimensions are in millimeters. Tolerances are  $\pm 0.25$  mm (0.01") unless otherwise noted.

## INTERNAL CIRCUIT DIAGRAM



**PIN CONNECTION**

<b>No.</b>	<b>CONNECTION</b>
1	ANODE ROW 5
2	ANODE ROW 7
3	CATHODE COLUMN 2
4	CATHODE COLUMN 3*1
5	ANODE ROW 4*2
6	CATHODE COLUMN 5
7	ANODE ROW 6
8	ANODE ROW 3
9	ANODE ROW 1
10	CATHODE COLUMN 4
11	CATHODE COLUMN 3*1
12	ANODE ROW 4*2
13	CATHODE COLUMN 1
14	ANODE ROW 2

NOTES : 1. Pin 4 & 11 are internally connected.

2. Pin 5 & 12 are internally connected.

**ABSOLUTE MAXIMUM RATING AT Ta=25°C**

PARAMETER	MAXIMUM RATING	UNIT
Average Power Dissipation Per Dot	40	mW
Peak Forward Current Per Dot	90	mA
Average Forward Current Per Dot	15	mA
Derating Linear From 25°C Per Dot	0.2	mA/°C
Reverse Voltage Per Dot	5	V
Operating Temperature Range	-35°C to +85°C	
Storage Temperature Range	-35°C to +85°C	
Solder Temperature: max 260°C for max 3sec at 1.6mm[1/16inch] below seating plane.		

**ELECTRICAL / OPTICAL CHARACTERISTICS AT Ta=25°C**

PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITION
Average Luminous Intensity	I <sub>v</sub>	1650	3500		μcd	I <sub>p</sub> =32mA 1/16Duty
Peak Emission Wavelength	λ <sub>p</sub>		650		nm	I <sub>F</sub> =20mA
Spectral Line Half-Width	Δλ		20		nm	I <sub>F</sub> =20mA
Dominant Wavelength	λ <sub>d</sub>		639		nm	I <sub>F</sub> =20mA
Forward Voltage Per Segment	V <sub>F</sub>		2.1	2.6	V	I <sub>F</sub> =20mA
Reverse Current any Dot	I <sub>R</sub>		2.3	2.8	μA	V <sub>R</sub> =5V
Luminous Intensity Matching Ratio	I <sub>v-m</sub>			2:1		I <sub>p</sub> =32mA 1/16Duty

Note: Luminous intensity is measured with a light sensor and filter combination that approximates the CIE (Commision Internationale De L'Eclairage) eye-response curve.

**TYPICAL ELECTRICAL / OPTICAL CHARACTERISTIC CURVES**

(25°C Ambient Temperature Unless Otherwise Noted)

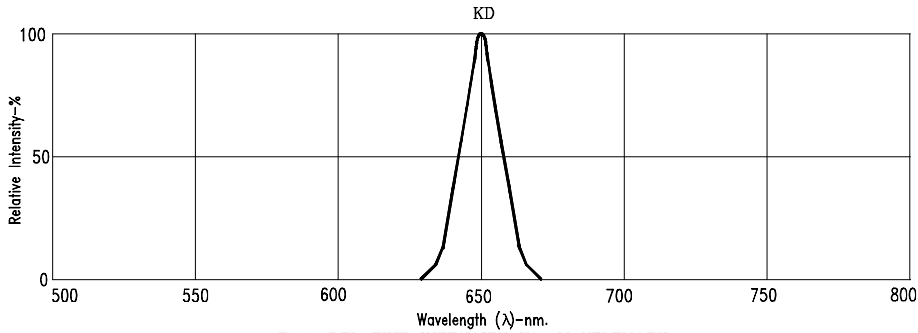


Fig1. RELATIVE INTENSITY VS. WAVELENGTH

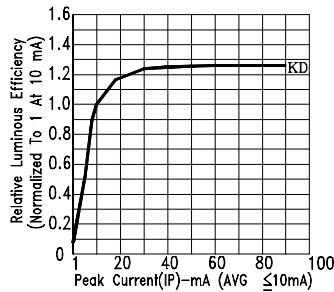


Fig2. RELATIVE LUMINOUS EFFICIENCY (LUMINOUS INTENSITY PER UNIT CURRENT) VS. PEAK CURRENT (REFRESH RATE 1KHz)

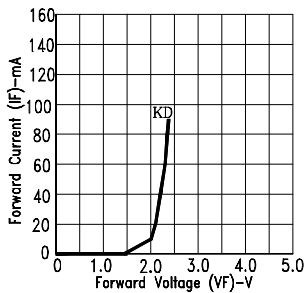


Fig3. FORWARD CURRENT VS. FORWARD VOLTAGE

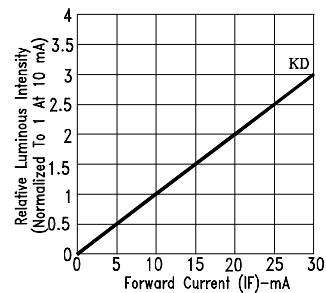


Fig4. RELATIVE LUMINOUS INTENSITY VS. FORWARD CURRENT

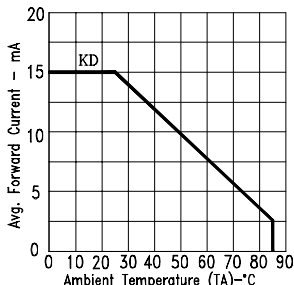


Fig5. MAX AVERAGE FORWARD CURRENT VS. AMBIENT TEMPERATURE.

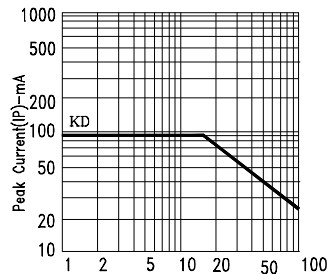


Fig6. MAX PEAK CURRENT VS. DUTY CYCLE % (REFRESH RATE 1KHz)

NOTE : KD=AlInGaP HYPER RED